Laboratory analogy of crystalline $Fe_2SiO_4, (FexFe1-x)_2SiO_4 \ \ \, and SiC \ \, grain$ formation

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A new evaporation method by the use of carbon holy film have been used on the formation of crystalline Fayalite (Fe₂SiO₄), Olivine(Mg_xFe_{1-x})2SiO₄ and SiC grains by the evaporation in inert gas of He or Ar. Solid crystalline grains less than 50 nm have been produced from gas phase. As reported in previous paper(T, Sato et al, Planetary and Space Science 54 (2006)612-616), Fe crystalline particle covered with SiO layer produced and Fe₂SiO₄ particle was produced by heating at 800°C. In the present paper, direct evaporation of mixture gas of (Fe, SiO), (Fe, Mg, SiO) and (Si, C) can be formed the crystalline particles from gas phase.



Fig1.Fe₂SiO₄

Fig2.(Mg,Fe)2SiO4



Fig3.SiC